# ST(意法) STTH20004TV1 PDF

# 深圳创唯电子有限公司

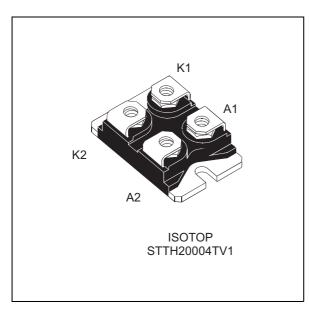
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### STTH20004TV1

### Ultrafast high voltage rectifier

Datasheet - production data



**Table 1. Device summary** 

Symbol	Value
I <sub>F(AV)</sub>	Up to 2 x 120 A
V <sub>RRM</sub>	400 V
T <sub>j</sub> (max)	150 °C
V <sub>F</sub> (typ)	0.83 V
t <sub>rr</sub> (max)	60 ns

### **Features**

- Ultrafast switching
- Low reverse current
- · Low thermal resistance
- · Reduces switching and conduction losses
- · Insulated package:
  - Electrical insulation = 2500 V rms
  - Capacitance = 189 pF
- ECOPACK®2 compliant component

### **Description**

The STTH20004TV1 uses ST new 400 V technology and is specially suited for use in switching power supplies, welding equipment, and industrial applications, as an output rectification diode.

**Characteristics** STTH20004TV1

#### **Characteristics** 1

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parar	Value	Unit		
$V_{RRM}$	Repetitive peak reverse voltage		400	V	
I <sub>F(RMS)</sub>	Forward rms current			200	Α
ı	Average forward current \$ - 0.5	T <sub>c</sub> = 75 °C	Per diode	100	Α
I <sub>F(AV)</sub>	Average forward current, $\delta = 0.5$	T <sub>c</sub> = 55 °C	Per diode	120	Α.
I <sub>FSM</sub>	Surge non repetitive forward current $t_p = 10 \text{ ms Sinusoidal}$				А
T <sub>stg</sub>	Storage temperature range	-55 to + 150	°C		
T <sub>j</sub>	Maximum operating junction temperature		150	°C	

**Table 3. Thermal parameter** 

Symbol	Parameter	Maximum	Unit	
D	Junction to case	Per diode	0.60	
R <sub>th(j-c)</sub>		Total	0.35	°C/W
R <sub>th(c)</sub>	Coupling		0.10	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j \text{ (diode1)}} = P_{\text{(diode1)}} \times R_{\text{th(j-c) (per diode)}} + P_{\text{(diode2)}} \times R_{\text{th(c)}}$ 

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V - V			100	μA
Reverse leakage current	T <sub>j</sub> = 125 °C	$V_R = V_{RRM}$		100	1000	μΑ	
V (2)	V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 100 A			1.2	W
VF'-7		T <sub>j</sub> = 150 °C	11F = 100 A		0.83	1.0	1 V

- 1. Pulse test:  $t_p$  = 5 ms,  $\delta$  < 2%
- 2. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the maximum conduction losses use the following equation: P = 0.8 x  $I_{F(AV)}$  + 0.002  $I_{F}^{2}_{(RMS)}$ 

STTH20004TV1 Characteristics

**Table 5. Dynamic characteristics** 

Symbol	Parameter	Parameter		Min.	Тур.	Max.	Unit
4			$I_F = 1 \text{ A},$ $dI_F/dt = 50 \text{ A}/\mu\text{s},$ $V_R = 30 \text{ V}$		75	100	ne
'rr	t <sub>rr</sub> Reverse recovery time T <sub>j</sub>	,	$I_F = 1 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 30 \text{ V}$		45	60	ns
t <sub>fr</sub>	Forward recovery time	T 05.00	$I_{f} = 100 \text{ A},$ $dI_{f}/dt = 200 \text{ A/}\mu\text{s}$ $V_{fR} = 1.1 \text{ x } V_{fmax}$			800	ns
V <sub>FP</sub>	Forward recovery voltage	1 <sub>j</sub> = 25 °C			2.6		V
I <sub>RM</sub>	Reverse recovery current	T 405.00	$I_F = 100 \text{ A},$ $dI_F/dt = 100 \text{ A/}\mu\text{s},$ $V_R = 200 \text{ V}$			18	Α
S <sub>factor</sub>		I <sub>j</sub> = 125 °C			0.4		-

Figure 1. Conduction losses versus average forward current (per diode)

Figure 2. Forward voltage drop versus forward current (per diode)

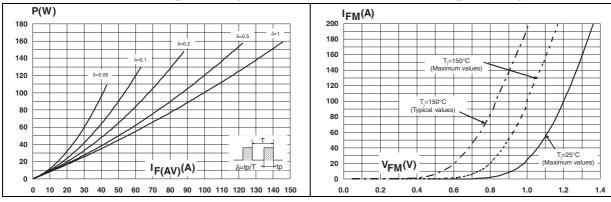
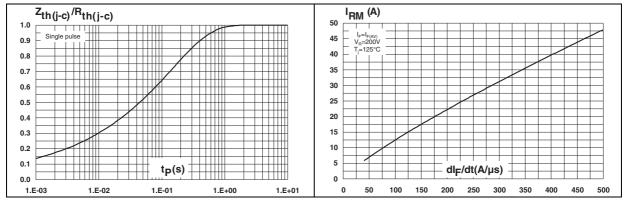


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

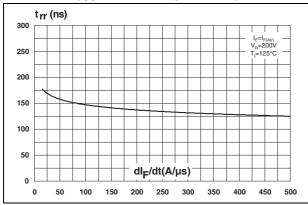
Figure 4. Peak reverse recovery current versus dl<sub>F</sub>/dt (typical values, per diode)



**Characteristics** STTH20004TV1

Figure 5. Reverse recovery time versus dl<sub>F</sub>/dt (typical values, per diode)

Figure 6. Reverse recovery charges versus dl<sub>F</sub>/dt (typical values, per diode)



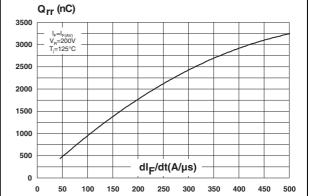
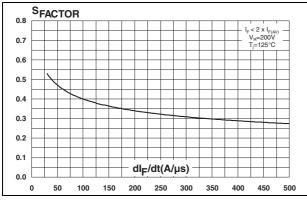
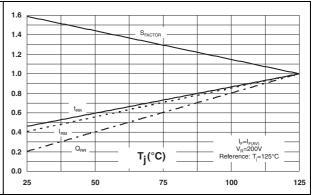


Figure 7. Reverse recovery time versus dl<sub>F</sub>/dt (typical values, per diode)

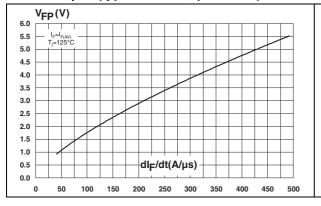
Figure 8. Relative variations of dynamic parameters versus junction temperature

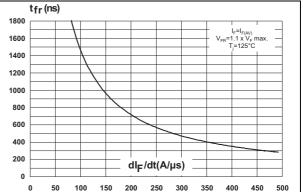




dl<sub>F</sub>/dt (typical values, per diode)

Figure 9. Transient peak forward voltage versus Figure 10. Forward recovery time versus dl<sub>F</sub>/dt (typical values, per diode)





STTH20004TV1 Characteristics

C(pF)
10000

F=1MHz
V<sub>0sc=30mV<sub>mMs</sub>
T<sub>=25°C</sub>

V<sub>R</sub>(V)</sub>

Figure 11. Reverse recovery time versus dl<sub>F</sub>/dt (typical values, per diode)



Package information STTH20004TV1

### 2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

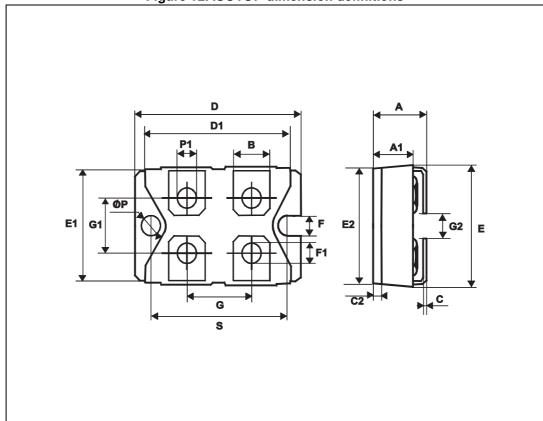


Figure 12. ISOTOP dimension definitions

**Table 6. ISOTOP dimension values** 

	Dimensions							
Ref.	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	11.80		12.20	0.465		0.480		
A1	8.90		9.10	0.350		0.358		
В	7.8		8.20	0.307		0.323		
С	0.75		0.85	0.030		0.033		
C2	1.95		2.05	0.077		0.081		
D	37.80		38.20	1.488		1.504		
D1	31.50		31.70	1.240		1.248		
Е	25.15		25.50	0.990		1.004		
E1	23.85		24.15	0.939		0.951		
E2		24.80			0.976			
G	14.90		15.10	0.587		0.594		
G1	12.60		12.80	0.496		0.504		
G2	3.50		4.30	0.138		0.169		
F	4.10		4.30	0.161		0.169		
F1	4.60		5.00	0.181		0.197		
Р	4.00		4.30	0.157		0.69		
P1	4.00		4.40	0.157		0.173		
S	30.10		30.30	1.185		1.193		

Ordering information STTH20004TV1

## 3 Ordering information

**Table 7. Ordering information** 

Order code	Marking	Package	Weight	Base qty <sup>(1)</sup>	Delivery mode
STTH20004TV1	STTH20004TV1	ISOTOP	27 g (without screws)	10 (with screws)	Tube

<sup>1.</sup> This product is supplied with 40 terminal screws and washers for each tube. The screws and washers are supplied in a separate pack with the order.

## 4 Revision history

**Table 8. Document revision history** 

Date	Revision	Changes
18-Oct-2005	1	First issue.
15-Sep-2011	2	Added insulated package information in Features.
20-Jun-2014	3	Updated ECOPACK® statement, Table 2 and Table 3.

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